

# S2S3/S2S4

## Mini-Flat Type Phototriac Coupler

### ■ Features

1. Popular type
2. Small package type
3. Conforming to UL double protective insulation ( $V_{iso}$  : 3 750V<sub>rms</sub>)
4. Infrared reflow soldering type (230°C, within 30 seconds)
5. Recognized by UL (No. 64380)

### ■ Model Line-ups

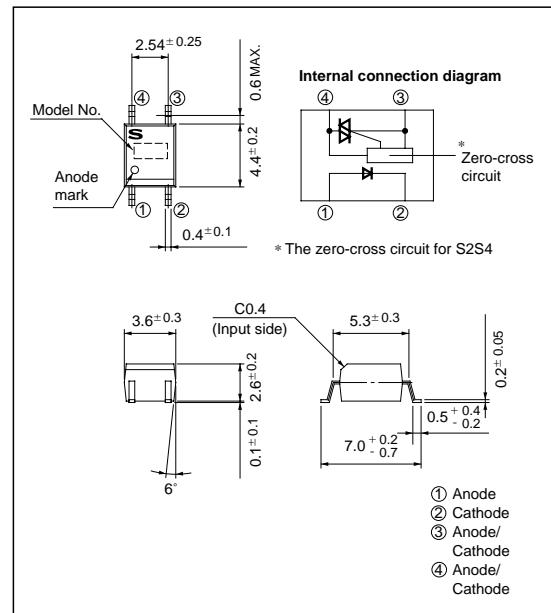
	For 100/200V line
Zero-cross circuit not built in	<b>S2S3</b>
Zero-cross circuit built in	<b>S2S4</b>

### ■ Application

1. For SSR

### ■ Outline Dimensions

(Unit : mm)



### ■ Absolute Maximum Ratings

(Ta=25°C)

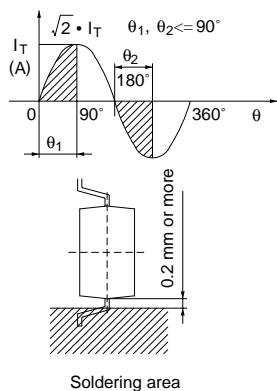
	Parameter	Symbol	Rating	Unit
Input	Forward current	I <sub>F</sub>	50	mA
	Reverse voltage	V <sub>R</sub>	6	V
Output	*1 RMS ON-state current	I <sub>T</sub>	0.05	A <sub>rms</sub>
	*2 Peak one cycle surge current	I <sub>surge</sub>	0.6 (50Hz sine wave)	A
	Repetitive peak OFF-state voltage	V <sub>DRM</sub>	600	V
	*3 Isolation voltage	V <sub>iso</sub>	3 750	V <sub>rms</sub>
	Operating temperature	T <sub>opr</sub>	-30 to +100	°C
	Storage temperature	T <sub>stg</sub>	-40 to +125	°C
	*4 Soldering temperature	T <sub>sol</sub>	260	°C

\*1 The definition of conduction angle  $\theta$  of RMS ON-state current I<sub>T</sub> should be as shown in the right drawing. For decrease curve, refer to Fig. 2.

\*2 50Hz sine wave

\*3 40 to 60% RH, AC for 1 minute

\*4 For 10 seconds



## ■ Electro-optical Characteristics

(Ta=25°C)

Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Input	Forward voltage	V <sub>F</sub>	I <sub>F</sub> = 20mA	-	1.2	1.4	V
	Reverse current	I <sub>R</sub>	V <sub>R</sub> = 3V	-	-	10	µA
Output	Repetitive peak OFF-state current	I <sub>IDRM</sub>	V <sub>DRM</sub> = Rated	-	-	1	µA
	ON-state voltage	V <sub>T</sub>	I <sub>T</sub> = 0.05A	-	-	2.5	V
	Holding current	I <sub>H</sub>	V <sub>D</sub> = 6V	0.1	-	3.5	mA
	Critical rate of rise of OFF-state voltage	dV/dt	V <sub>DRM</sub> = $1/\sqrt{2} \cdot$ Rated	100	1 000	-	V/µs
	Zero-cross voltage	S2S4	V <sub>OX</sub>	I <sub>F</sub> = 15mA, Resistance load	-	35	V
	Minimum trigger current	I <sub>FT</sub>	V <sub>D</sub> = 6V, R <sub>L</sub> = 100Ω	-	-	10	mA
Transfer characteristics	Insulation resistance	R <sub>ISO</sub>	DC500V, 40 to 60% RH	5 x 10 <sup>10</sup>	1 x 10 <sup>11</sup>	-	Ω
	Turn-on time	S2S3	ton	V <sub>D</sub> = 6V, R <sub>L</sub> = 100Ω , I <sub>F</sub> = 20mA	-	100	µs
	S2S4	-		-	50		

Fig. 1 Forward Current vs. Ambient Temperature

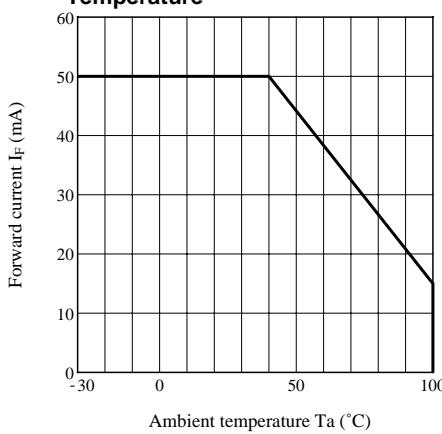


Fig. 2 RMS ON-state Current vs. Ambient Temperature

